

2SC4242

NPN SILICON TRANSISTOR

SWITCHMODE SERIES NPN POWER TRANSISTORS

DESCRIPTION

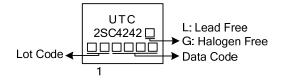
The UTC 2SC4242 is a high-voltage, high-speed switching power transistor and designed particularly for 115 and 220V switch mode applications, such as switching regulators, inverters, DC-DC converter and general purpose power amplifiers.

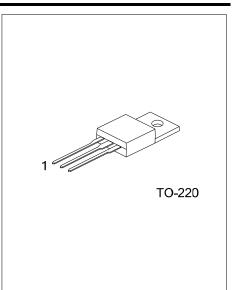
FEATURES

- * Low saturation voltage.
- * Switching time: t_F=0.5µs (Max.)@ I_C=5.0A

High reliability						
ORDERING INFO	RMATION					
Ordering Number		Deelvere	Pin Assignment			Decking
Normal	Lead Free Plating	Package	1	2	3	Packing
2SC4242-TA3-T	2SC4242L-TA3-T	TO-220	В	С	Е	Tube
lote: Pin Assignment: B: Ba	se C: Collector E: En	nitter				
2SC4242L- <u>TA3-T</u>	(1) T: Tube (2) TA3: TO- (3) L: Lead F				3ad Free	

MARKING





■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage		V _{CEO}	400	V
Collector-Base Voltage		V _{CBO}	450	V
Emitter-Base Voltage		V _{EBO}	8.0	V
Collector Current	Continuous	Ιc	7.0	А
	Peak	I _{CM}	14	А
Base Current		Ι _Β	2.0	А
Total Power Dissipation @T _C =25°C Derate Above 25°C		Р	40	W
		PD	0.32	W/°C
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Thermal Resistance Junction -Case	θ _{JC}	4	°C/W

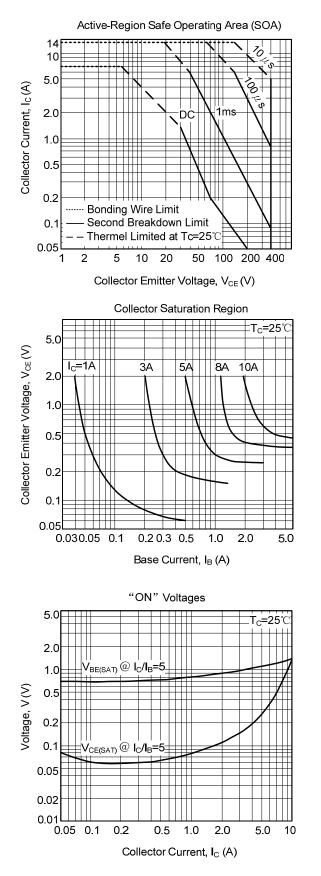
ELECTRICAL CHARACTERISTICS (T_c=25°C, unless otherwise specified)

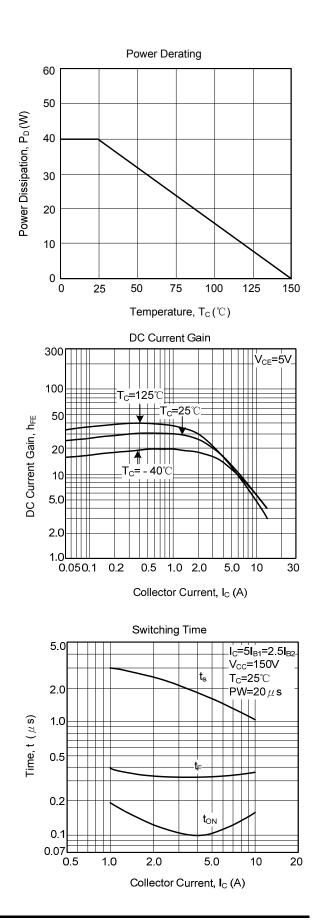
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Collector-Emitter Sustaining Voltage	BV_{CEO}	I _{CEO} =100mA, I _B =0	400			V		
Collector-Base Breakdown Voltage	BV_{CBO}	I _{CBO} =1.0mA, I _E =0	450			V		
Emitter-Base Breakdown Voltage	BV_{EBO}	I _{EBO} =1.0mA, I _C =0	8.0			V		
Collector Cutoff Current	I _{CBO}	V _{CBO} =450V, I _E =0			100	μA		
Emitter Cutoff Current	I _{EBO}	V _{EBO} =8.0V, I _C =0			100	μA		
ON CHARACTERISTICS								
DC Current Gain	h _{FE}	I _C =4.0A, V _{CE} =5.0V	10					
Collector-Emitter Saturation Voltage	V _{CE (SAT)}	I _C =4.0A, I _B =800mA			0.8	V		
Base-Emitter Saturation Voltage	V _{BE (SAT)}	I _C =4.0A, I _B =800mA			1.2	V		
SWITCHING CHARACTERISTICS								
On Time	t _{ON}				1.0	μs		
Storage Time	t _s	V _{CC} =150V, I _C =5.0A I _{B1} = -I _{B2} =1.0A, R _I =30Ω			2.5	μs		
Fall Time	t _F	$I_{B1} - I_{B2} - I.0A, R_{L} = 3002$			0.5	μs		

Note: Pulse Test: Pulse Width=300µs, Duty Cycle ≤ 2.0%



TYPICAL CHARACTERISTIC





UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

